

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/681,108	10/09/2003	Chandra Mouli	M4065.0762/P762	8110
24998	7590 07/01/2005		EXAM	INER
DICKSTE	N SHAPIRO MORIN	THAI, LUAN C		
2101 L Stree	•		ART UNIT	PAPER NUMBER
Washington, DC 20037			ARTONII	TATER NUMBER
			2891	

DATE MAILED: 07/01/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

		·
	Application No.	Applicant(s)
Office Action Summer:	10/681,108	MOULI, CHANDRA
Office Action Summary	Examiner	Art Unit
	Luan Thai	2891
The MAILING DATE of this communication a Period for Reply	appears on the cover sheet w	vith the correspondence address
A SHORTENED STATUTORY PERIOD FOR REI THE MAILING DATE OF THIS COMMUNICATIOI - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a - If NO period for reply is specified above, the maximum statutory peri - Failure to reply within the set or extended period for reply will, by sta Any reply received by the Office later than three months after the may earned patent term adjustment. See 37 CFR 1.704(b).	N. 1.136(a). In no event, however, may a reply within the statutory minimum of thi od will apply and will expire SIX (6) MOI tute, cause the application to become A	reply be timely filed rty (30) days will be considered timely. NTHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).
Status		
1) Responsive to communication(s) filed on 24	LMay 2005	
· · · · · · · · · · · · · · · · · · ·	his action is non-final.	
3) Since this application is in condition for allow		ters, prosecution as to the merits is
closed in accordance with the practice unde		
Disposition of Claims		
4) ☐ Claim(s) 1-26 is/are pending in the application 4a) Of the above claim(s) 20-26 is/are withden 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-19 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and	rawn from consideration.	
Application Papers	·	
9)☐ The specification is objected to by the Exami		
10)☐ The drawing(s) filed on is/are: a)☐ a		
Applicant may not request that any objection to the		• •
Replacement drawing sheet(s) including the correction is a biasted to but the		· · · · · · · · · · · · · · · · · · ·
11)☐ The oath or declaration is objected to by the	Examiner. Note the attache	d Office Action or form PTO-152.
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the priority docume application from the International Bure * See the attached detailed Office action for a life.	ents have been received. ents have been received in A riority documents have been eau (PCT Rule 17.2(a)).	Application No received in this National Stage
Attachment(s)		
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948)		Summary (PTO-413)
 Notice of Dransperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0 Paper No(s)/Mail Date 7/12/04. 		s)/Mail Date nformal Patent Application (PTO-152)
Detection 17 to 1 0 m		

Application/Control Number: 10/681,108 Page 2

Art Unit: 2891

DETAILED ACTION

Election/Restrictions

1. Applicant's election *traverse* of group I filed May 24, 2005 is acknowledged. Since the traverse is found persuasive, the restriction mailed May 16, 2005 is withdrawn.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 1-2, 4-5, 7-9, 11-13, 15-17, and 19 are rejected under 35 U.S.C. 102(e) as being anticipated by Mouli et al. (US 2004/0251398).

The figures and reference numbers referred to in this office action are used merely to indicate an example of a specific teaching and are not to be taken as limiting.

Regarding claims 1-2, 4-5, 7-9, 11-13, 15-17, and 19, Mouli et al. (see specifically figures 9-15) disclose a photoconversion device (e.g., photodiode 199/299/399) comprising: a substrate (110) having a surface; a first doped region (188) having a first conductivity type (e.g., p-type) and located below the surface of the substrate at an ultra-shallow depth, wherein the first doped region is doped with indium (paragraph [0060]); and a second doped region (126) having a second conductivity type (e.g., n-type) located beneath the first doped region (188) for

Application/Control Number: 10/681,108 Page 3

Art Unit: 2891

producing photo-generated charges, wherein the concentration of said indium dopant is in the range of about 1 x 10¹⁸/cm3 to 5 x 10¹⁸/cm3 (paragraph [0062]). Mouli et al. further teach the first and second doped regions both including indium ions, the indium ions in the first region acting as electron acceptors, the indium ions in the second region acting as electron donors. Mouli et al. also disclose a processing system (see figure 15) comprising: a processor (644); and an imager (642), as described above, coupled to the processor, a readout circuit comprising at least an output transistor formed on the substrate (see paragraphs [0068], [0069], [0070], and [0071]).

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 3, 6, 10, 14 and 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Mouli et al. (US 2004/0251398).

The figures and reference numbers referred to in this office action are used merely to indicate an example of a specific teaching and are not to be taken as limiting.

Regarding claims 3, 6, 10, 14 and 18, Mouli et al. disclose the claimed invention as detailed above except for teaching the doped region being implanted at a depth in the range of about 800 Å. However, the depth of the doped region is a result effective variable that one of ordinary skill in the art would optimize for forming the photodiode in a semiconductor device. Therefore, it would have been obvious to one of ordinary skill in the art at the time of invention

Application/Control Number: 10/681,108

Art Unit: 2891

was made to have the doped region at the depth in the range of 800 Å, in order to form an adequate photodiode in a semiconductor device, and since it has been held that discovering the optimum value of a result effective variable involves only routine skill in the art. In re Boesch, 617 F. 2d 272, 205 USPQ 215 (CCPA 1980).

Page 4

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Luan Thai whose telephone number is 571-272-1935. The examiner can normally be reached on 6:30 AM - 5:00 PM, Monday to Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Bradley W. Baumeister can be reached on 571-272-1722. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Luan Thai

Primary Examiner Art Unit 2891

June 27, 2005